

Electronic Acknowledgement Receipt

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Application Number:	10577175
International Application Number:	
Confirmation Number:	3451
Title of Invention:	Method for Self-Supported Transfer of a Fine Layer by Pulsation after Implantation or Co-Implantation
First Named Inventor/Applicant Name:	Nguyet-Phuong Nguyen
Customer Number:	90678
Filer:	Jasper W. Dockrey/Nkosi Harvey
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Application Type:	U.S. National Stage under 35 USC 371

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File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1	NPL Documents	Picraux_S_Thomas_et_al_Ion_I mplantation_of_Surfaces.pdf	623657 c603c27f2f7fb0132a9edc7afe2a3e24a18b1 0ea	no	9

Warnings:

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2	NPL Documents	Popov-VP-Blistering-On-A-Silicon-Surface_1.PDF	502658	no	9
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3	NPL Documents	Primak_W-Impurity_Effect_In_the_Ionization_Dilation_of_Vitreous_Silica.pdf	792830	no	8
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4	NPL Documents	Ray-et-al_1.pdf	626028	no	8
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5	NPL Documents	Renier_M_et_al_A_New_Low-energy_Ion_Implanter.pdf	82450	no	2
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8	NPL Documents	Sah_Chieh-Tang_et_al-Deactivation_of_the_Boron_Acceptor_in_Silicon_by_Hydrogen.pdf	300754	no	3
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Total Files Size (in bytes):			28365527		
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